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# RJK0331DPB

# Silicon N Channel Power MOS FET Power Switching

REJ03G1640-0400 Rev.4.00 Apr 10, 2008

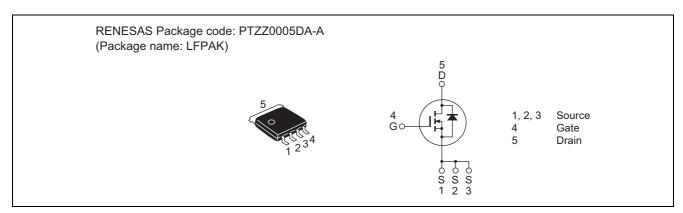
### **Features**

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)} = 2.6 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$ 

• Pb-free

### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	30	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	40	А
Drain peak current	I <sub>D(pulse)</sub> Note1	160	А
Body-drain diode reverse drain current	I <sub>DR</sub>	40	А
Avalanche current	I <sub>AP</sub> Note 2	20	А
Avalanche energy	E <sub>AR</sub> Note 2	40	mJ
Channel dissipation	Pch Note3	50	W
Channel to Case Thermal Resistance	θch-C	2.5	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

3. Tc = 25°C

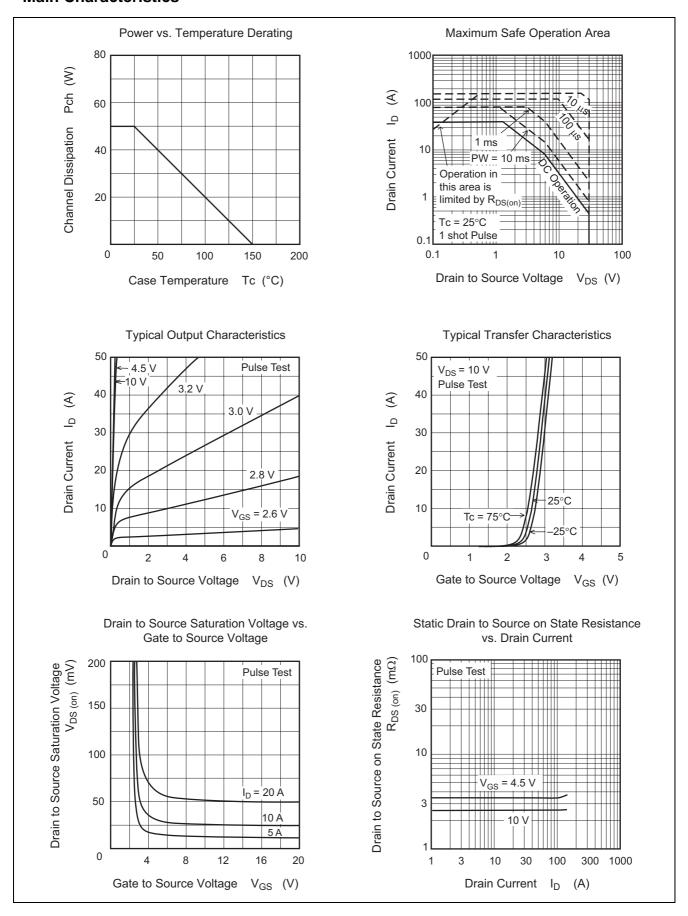
### **Electrical Characteristics**

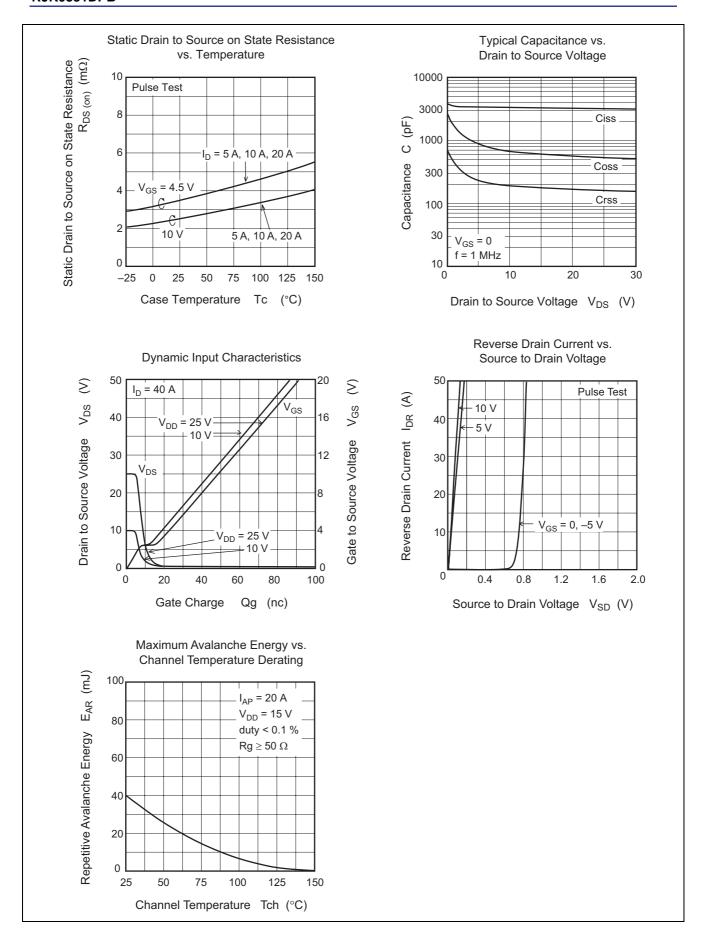
 $(Ta = 25^{\circ}C)$ 

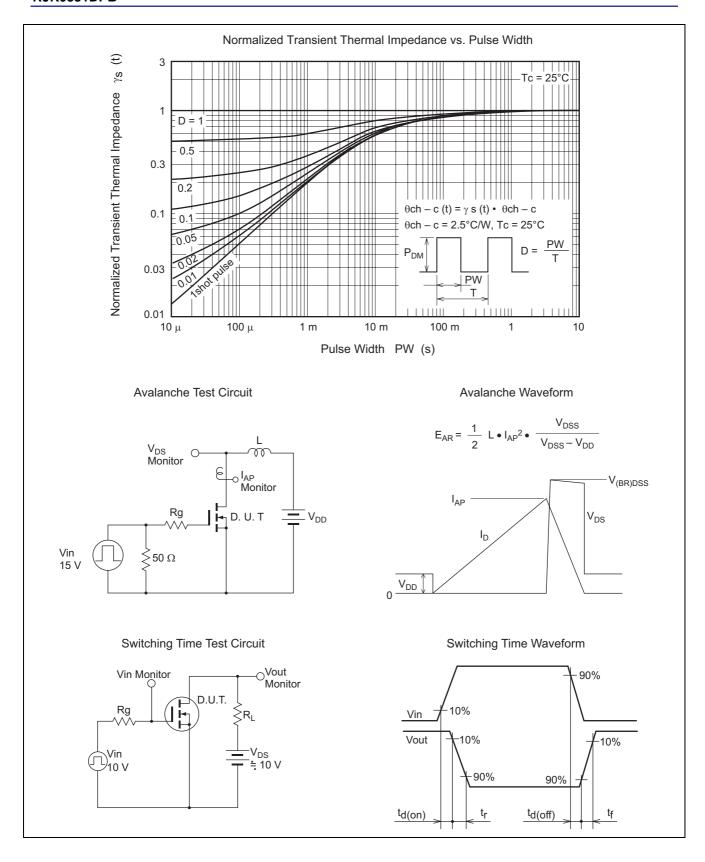
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	2.6	3.4	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R <sub>DS(on)</sub>	_	3.5	4.9	mΩ	$I_D = 20 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y <sub>fs</sub>	_	80	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	3380	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	660	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	190	_	pF	
Gate Resistance	Rg	_	0.6	_	Ω	
Total gate charge	Qg	_	22	_	nC	$V_{DD} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$
Gate to source charge	Qgs	_	7.8	_	nC	I <sub>D</sub> = 40 A
Gate to drain charge	Qgd	1	4.8	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	1	5.8	_	ns	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A},$
Rise time	t <sub>r</sub>	1	3.9	_	ns	$V_{DD} \cong 10 \text{ V}, R_L = 0.5 \Omega,$
Turn-off delay time	t <sub>d(off)</sub>	1	45	_	ns	$Rg = 4.7 \Omega$
Fall time	t <sub>f</sub>		4.6	_	ns	
Body-drain diode forward voltage	$V_{DF}$	1	0.82	1.07	V	$I_F = 40 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body–drain diode reverse recovery time	t <sub>rr</sub>	1	30	_	ns	$I_F = 40 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/ \mu \text{s}$
Body–drain diode reverse recovery charge	Q <sub>rr</sub>	_	26	_	nC	

Notes: 4. Pulse test

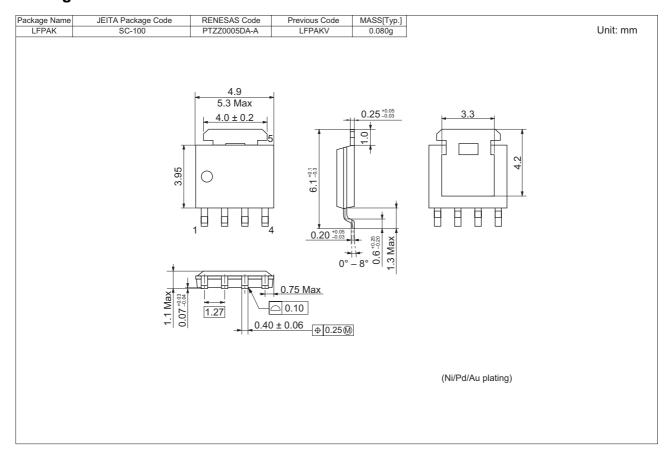
### **Main Characteristics**







### **Package Dimensions**



### **Ordering Information**

Part No.	Quantity	Shipping Container
RJK0331DPB-00-J0	2500 pcs	Taping

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